

# N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}(\Omega)$	I <sub>D</sub> (A)		
30	0.0135 at V <sub>GS</sub> = 10 V	10		
	0.020 at V <sub>GS</sub> = 4.5 V	8		

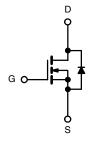
#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET<sup>®</sup> Power MOSFET
- 100 % R<sub>q</sub> Tested
- Compliant to RoHS Directive 2002/95/EC



#### **APPLICATIONS**

- · Battery Switch
- · Load Switch



N-Channel MOSFET

		SO-8	
S [ S [ G [	1 2 3 4		8 D 7 D 6 D 5 D
		Top View	

Ordering Information: Si4410BDY-T1-E3 (Lead (Pb)-free)

Si4410BDY-T1-GE3 (Lead (Pb)-free and Halogen-free)

<b>ABSOLUTE MAXIMUM RATINGS</b> T	$_A$ = 25 °C, unle	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	30		V
Gate-Source Voltage		V <sub>GS</sub>	± 20		
Continuous Proin Current /T 150 °C\8	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	10	7.5	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		8	6	٨
Pulsed Drain Current (10 μs Pulse Width)		I <sub>DM</sub>	50		Α
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	2.3	1.26	
	T <sub>A</sub> = 25 °C	P <sub>D</sub>	2.5	1.4	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		1.6	0.9	VV
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum boration to Ambienta	t ≤ 10 s	R <sub>thJA</sub>	40	50	
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	¹ ¹thJA	70	90	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	$R_{thJF}$	25	30	

#### Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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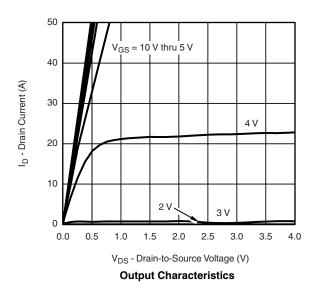
Parameter	Symbol	Test Conditions	Тур.	Max.	Unit	
Static	<u> </u>		·!	<u> </u>	l l	
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.0		3.0	٧
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		± 100	nA
Zero Gate Voltage Drain Current		$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}$			1	μΑ
	IDSS	$V_{DS} = 30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			5	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			Α
Drain-Source On-State Resistance <sup>a</sup>	В	$V_{GS} = 10 \text{ V}, I_D = 10 \text{ A}$		0.011	0.0135	
	R <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 5 \text{ A}$		0.0165	0.020	Ω
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_{D} = 10 \text{ A}$		25		S
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_S = 2.3 \text{ A}, V_{GS} = 0 \text{ V}$		0.76	1.1	V
Dynamic <sup>b</sup>	L L			<u> </u>	<u> </u>	
Gate Charge	Q <sub>g</sub>	$V_{DS} = 15 \text{ V}, V_{GS} = 5 \text{ V}, I_{D} = 10 \text{ A}$		13	20	
Total Gate Charge	Q <sub>gt</sub>			25	40	•
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 10 \text{ A}$		5.5		nC
Gate-Drain Charge	Q <sub>gd</sub>			3.7		
Gate Resistance	R <sub>g</sub>	f = 1 MHz		1.6	2.7	Ω
Turn-On Delay Time	t <sub>d(on)</sub>			10	15	
Rise Time	t <sub>r</sub>	$V_{DD}$ = 25 V, $R_L$ = 25 $\Omega$		10	15	1
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$		40	60	ns
Fall Time	t <sub>f</sub>			15	25	113
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	$I_F = 2.3 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}$		35	70	

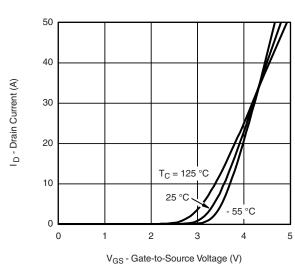
#### Notes:

- a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

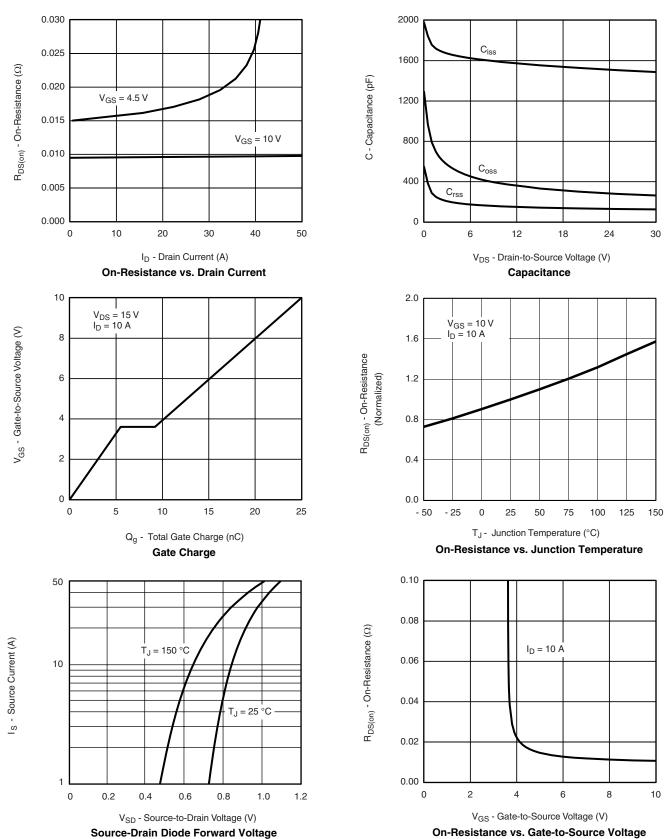




**Transfer Characteristics** 



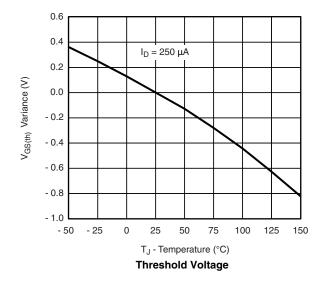
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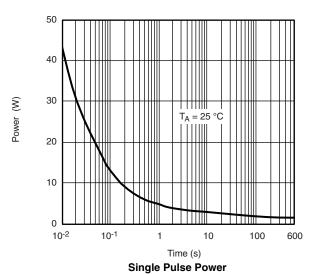


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## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

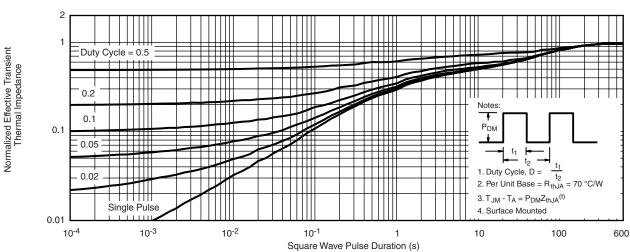




Limited by  $R_{DS(on)}^*$  100  $\mu$ s, 10  $\mu$ s

10

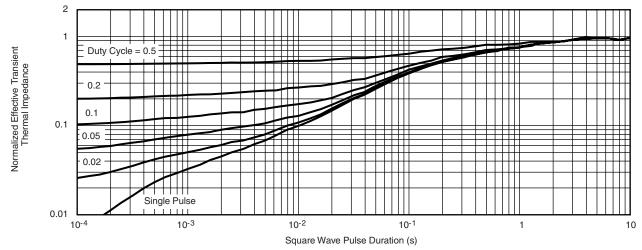
Safe Operating Area, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient



## TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Foot

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <a href="https://www.vishay.com/ppg?72211">www.vishay.com/ppg?72211</a>.

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